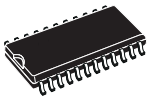
HCF4097B

ANALOG DIFFERENTIAL 8 CHANNEL MULTIPLEXER/DEMULTIPLEXER

- LOW ON RESISTANCE : 125Ω (Typ.) OVER 15V p-p SIGNAL INPUT RANGE FOR V_{DD} - V_{SS} = 15V
- HIGH OFF RESISTANCE : CHANNEL LEAKAGE OF 10pA (Typ.) at V_{DD} - V_{SS} = 10V
- MATCHED SWITCH CHARACTERISTICS : ΔR_{ON} = 5Ω (Typ.) FOR V_{DD} - V_{SS} =15V
- VERY LOW QUIESCENT POWER DISSIPATION UNDER A DIGITAL CONTROL INPUT AND SUPPLY CONDITIONS : 0.2μW (Typ.) at V_{DD} - V_{SS} = 10V
- BINARY ADDRESS DECODING ON CHIP
- QUIESCENT CURRENT SPECIFIED UP TO 20V
- STANDARDIZED SYMMETRICAL OUTPUT CHARACTERISTICS
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT I_I = 100nA (MAX) AT V_{DD} = 18V T_A = 25°C
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B "STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"



SOP

ORDER CODES

PACKAGE	TUBE	T & R
SOP	HCF4097BM1	HCF4097M013TR

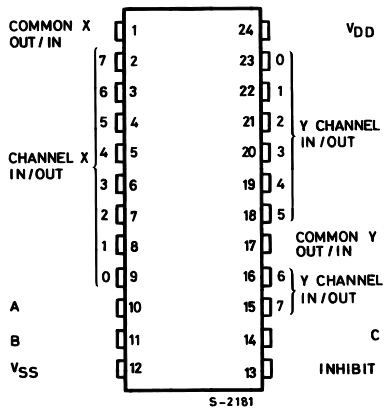
DESCRIPTION

HCF4097B is monolithic integrated circuits fabricated in Metal Oxide Semiconductor technology available in SOP package.

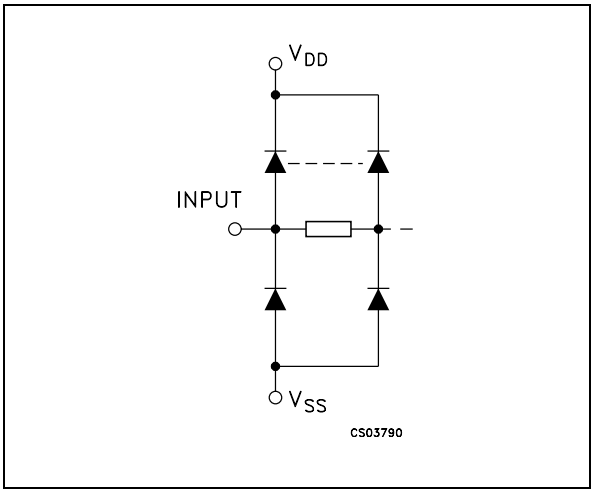
HCF4097B, a analog multiplexer/demultiplexer CMOS, is a digitally controlled analog switches device having low ON impedance, low OFF leakage current and internal address decoding. in addition, the ON resistance is relatively constant over the full input-signal range.
HCF4097B is a differential 8-channel multiplexer having three binary control inputs A, B, C, and an inhibit input. The inputs permit selection of one of eight pairs of switches. A logic "1" present at the inhibit input turns all channels off.

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PIN CONNECTION



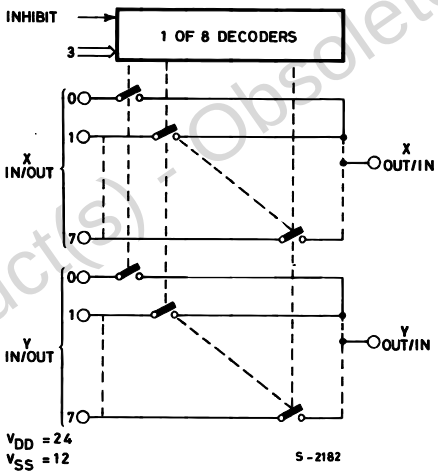
INPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
10, 11, 14	A, B, C	Binary Control Inputs
1	COMMON X OUT/IN	Common X Out/In
17	COMMON Y OUT/IN	Common Y Out/In
13	INHIBIT	Inhibit Input
9, 8, 7, 6, 5, 4, 3, 2	0 to 7 CHANNEL IN/OUT X	8 X channel In/Out
23, 22, 21, 20, 19, 18, 16, 15	0 to 7 CHANNEL IN/OUT Y	8 Y channel In/Out
12	V_{SS}	Negative Supply Voltage
24	V_{DD}	Positive Supply Voltage

FUNCTIONAL DIAGRAM

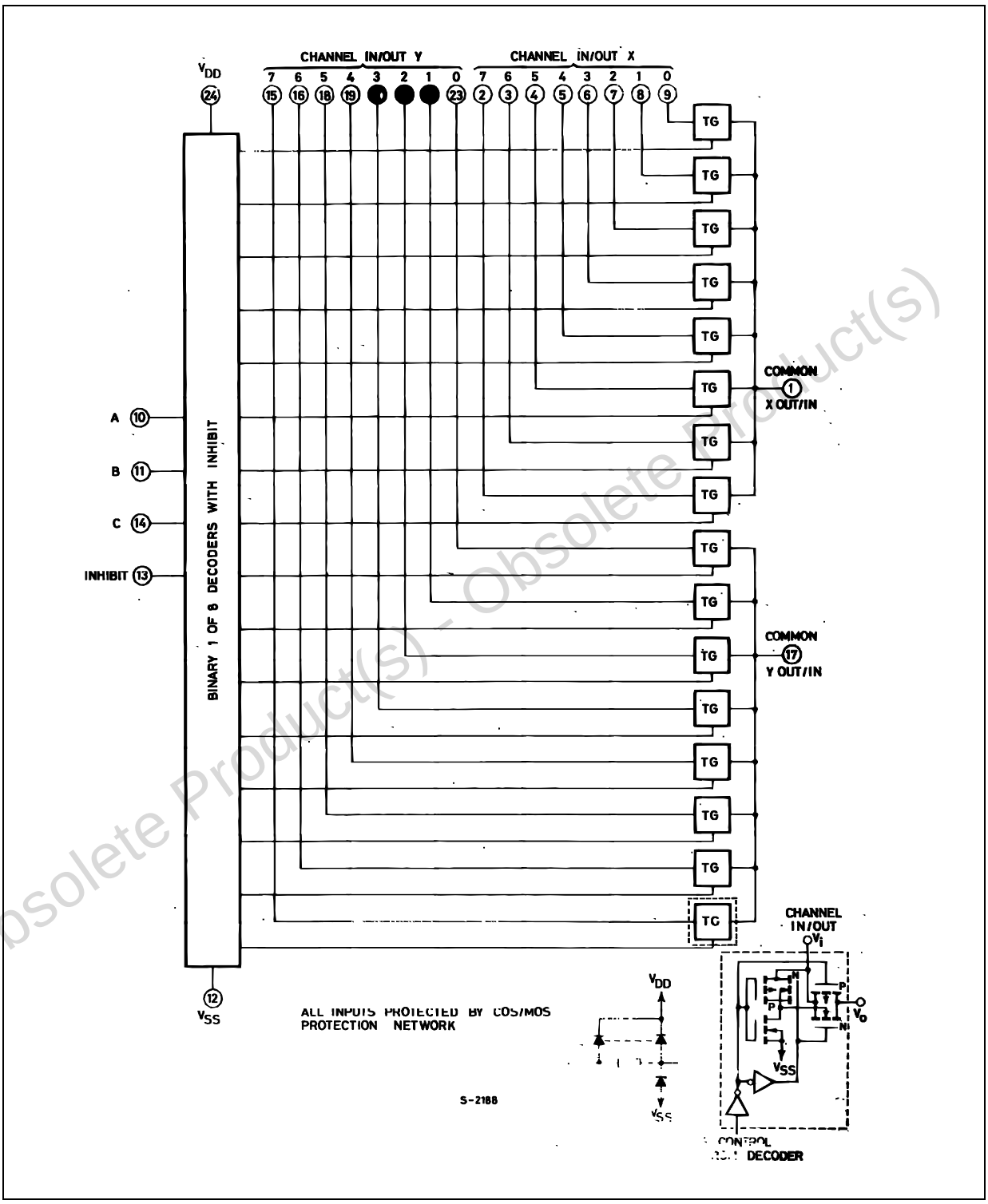


TRUTH TABLE

A	B	C	INH	SELECTED CHANNEL
X	X	X	H	NONE
L	L	L	L	0X 0Y
H	L	L	L	1X 1Y
L	H	L	L	2X 2Y
H	H	L	L	3X 3Y
L	L	H	L	4X 4Y
H	L	H	L	5X 5Y
L	H	H	L	6X 6Y
H	H	H	L	7X 7Y

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LOGIC DIAGRAM



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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	-0.5 to +22	V
V_I	DC Input Voltage	-0.5 to V_{DD} + 0.5	V
I_I	DC Input Current	± 10	mA
P_D	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T_{op}	Operating Temperature	-55 to +125	°C
T_{stg}	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V_{SS} pin voltage.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	3 to 20	V
V_I	Input Voltage	0 to V_{DD}	V
T_{op}	Operating Temperature	-55 to 125	°C

Obsolete Product(s) - Obsolete Product(s)

STATIC ELECTRICAL CHARACTERISTICS

(T_{amb} = 25°C,Typical temperature coefficient for all V_{DD} value is 0.3 %/°C)

Symbol	Parameter	Test Condition				Value							Unit
		V_{IS} (V)	V_{EE} (V)	V_{SS} (V)	V_{DD} (V)	T_A = 25°C			-40 to 85°C		-55 to 125°C		
						Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
I_L	Quiescent Supply Current				5		0.04	5		150		150	µA
					10		0.04	10		300		300	
					15		0.04	20		600		600	
					20		0.08	100		3000		3000	
SWITCH													
R_{ON}	On Resistance	$0 \le V_I \le V_{DD}$	0	0	5		470	1050		1200		1200	Ω
					10		180	400		500		520	
					15		125	240		300		300	
Δ_{ON}	Resistance Δ_{RON} (between any 2 of 4 switches)		0	0	5		10						Ω
					10		10						
					15		5						
OFF (•)	Channel Leakage Current Any Channel Off		0	0	18		±0.1	100		1000		1000	µA
	Channel Leakage Current All Channel Off (Common Out/In)		0	0	18		±0.1	100		1000		1000	
C	Capacitance Input			-5	5		5						pF
	Output capacitance						35						
	Feedthrough						0.2						
CONTROL													
V_{IL}	Input Low Voltage	= VDD thru 1KΩ	V_{EE} = V_{SS} R_L = 1KΩ to V_{SS} I_{IS} < 2µA (on all OFF channels)		5			1.5		1.5		1.5	V
					10			3		3		3	
					15			4		4		4	
V_{IH}	Input High Voltage				5	3.5			3.5		3.5		V
					10	7			7		7		
					15	11			11		11		
I_I	Input Leakage Current	V_I = 0/18V			18		$\pm 10^{-3}$	±0.1		±1		±1	µA
C_I	Input Capacitance	Any Address or Inhibit Input					5	7.5					pF

The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD}=5V, 2V min. with V_{DD}=10V, 2.5V min. with V_{DD}=15V

• Determined by minimum feasible leakage measurement for automating testing

Obsolete Product(s) - Obsolete Product(s)

DYNAMIC ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C, C_L = 50pF, R_L = 200KΩ, $t_r = t_f$ = 20 ns)

Symbol	Parameter	Test Condition							Value*		Unit
		V_C (V)	R_L (KΩ)	f_I (KHz)	V_I (V)	V_{SS} (V)	V_{DD} (V)		Typ.	Max.	
SWITCH											
t_{pd}	Propagation Delay Time (Signal Input to Output)	= V_{DD}	200		⎍	0	5		30	60	ns
							10		15	30	
							15		11	20	
	Frequency Response Channel "ON" (Sine Wave Input) at $20 \text{ Log } \frac{V_O}{V_I} = -3dB$	= V_{DD}	1		5 (•)	0	10	V_O at Common Out/In	20		ns
								V_O at Any Channel	60		
	Feedthrough (All channels OFF) at $20 \text{ Log } \frac{V_O}{V_I} = -40dB$	= V_{SS}	1		5 (•)	0	10	V_O at Common Out/In	12		MHz
								V_O at Any Channel	8		
	Frequency Signal Crosstalk at $20 \text{ Log } \frac{V_{O(A)}}{V_{I(B)}} = -40dB$	$V_{C(A)}$ = V_{DD} $V_{C(B)}$ = V_{SS}	1		5 (•)	0	10	Between Any two (A and B) Channels	1		MHz
								Between Sections (A and B) Measured on Common	10		
								Between Sections (A and B) Measured on any Channel	18		
t_W	Sine Wave Distortion (f_{IS} = 1KHz sine wave)	5	10	1	2 (•)	0	5		0.3		%
		10			3 (•)		10		0.2		
		15			5 (•)		15		0.12		
CONTROL(Address or Inhibit)											
t_{PLH}, t_{PHL}	Propagation Delay Time:Address or Inhibit to Signal OUT (Channel Turning ON)	⎍	1			0	5		325	650	ns
							10		135	270	
							15		95	190	
t_{PLH}, t_{PHL}	Propagation Delay Time:Address or Inhibit to Signal OUT (Channel Turning OFF)	⎍	0.3			0	5		220	440	ns
							10		90	180	
							15		65	130	
	Address or Inhibit to Signal Crosstalk	⎍	10**			0	10		75		mV peak

(*) Typical temperature coefficient for all V_{DD} value is 0.3 %/°C
(**) : Both Ends of Channel
(•) : Peak to Peak voltage symmetrical about (V_{DD} - V_{SS}) / 2

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APPLICATION INFORMATION

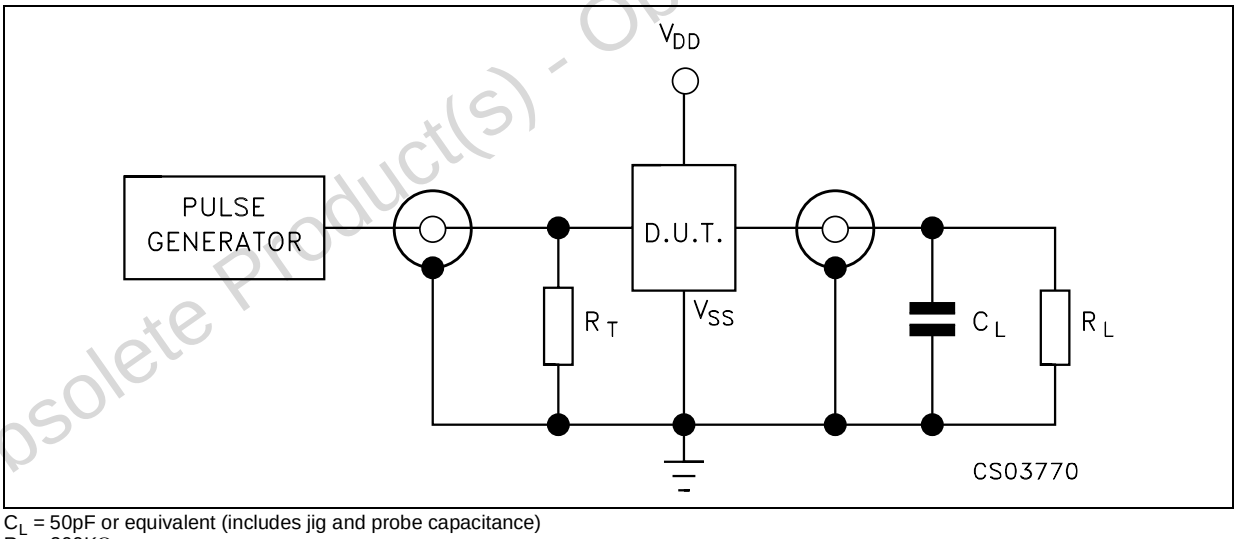
In applications where separate power sources are used to drive V_{DD} and the signal inputs, the V_{DD} current capability should exceed V_{DD}/R_L (R_L = effective external load). This provision avoids permanent current flow or clamp action on the V_{DD} supply when power is applied or removed from the HCF4097B.

When switching from one address to another, some of the ON periods of the channels of the multiplexers will overlap momentarily, which may be objectionable in certain applications. Also, when a channel is turned ON or OFF by an address input, there is a momentary conductive path from the channel to V_{SS}, which will dump some charge from any capacitor connected to the input or output of the channel. The inhibit input turning on a channel will similarly dump some charge to V_{SS}.

The amount of charge dumped is mostly a function of the signal level above V_{SS}. Typically, at $V_{DD} - V_{SS} = 10V$, a 100 pF capacitor connected to the input or output of the channel will lose 3-4% of its voltage at the moment the channel turns ON or OFF. This loss of voltage is essentially independent of the address or inhibit signal transition time, if the transition time is less than 1-2 ms. When the inhibit signal turns a channel off, there is no change dumping of V_{SS}. Rather, there is a slight rise in the channel voltage level (65 mV typ.) due to the capacitance coupling from inhibit input to channel input or output. Address input also couple some voltage steps onto the channel signal levels.

In certain applications, the external load-resistor current may include both V_{DD} and signal line components. To avoid drawing V_{DD} current when switch current flows into the transmission gate inputs, the voltage drop across the bidirectional switch must not exceed 0.8V (calculated from R_{ON} values shown in ELECTRICAL CHARACTERISTICS CHART). No V_{DD} current will flow through R_L if the switch current flows into terminal 1 on the HCF4097B.

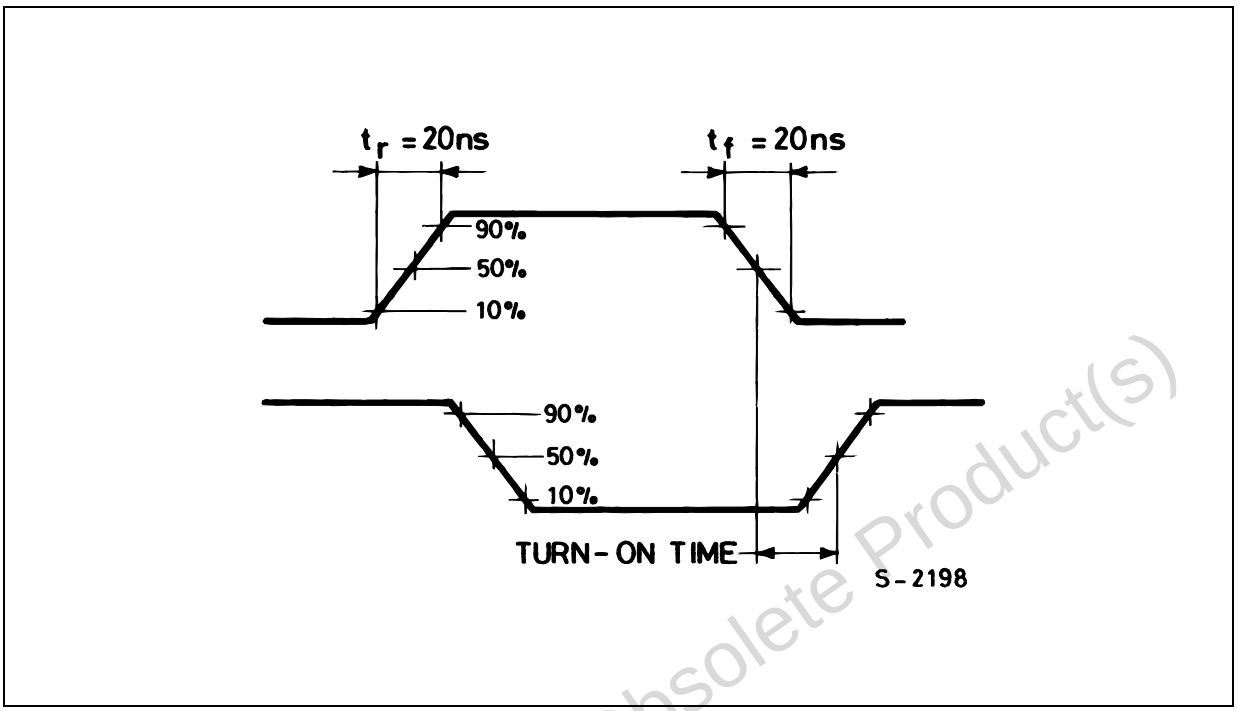
TEST CIRCUIT



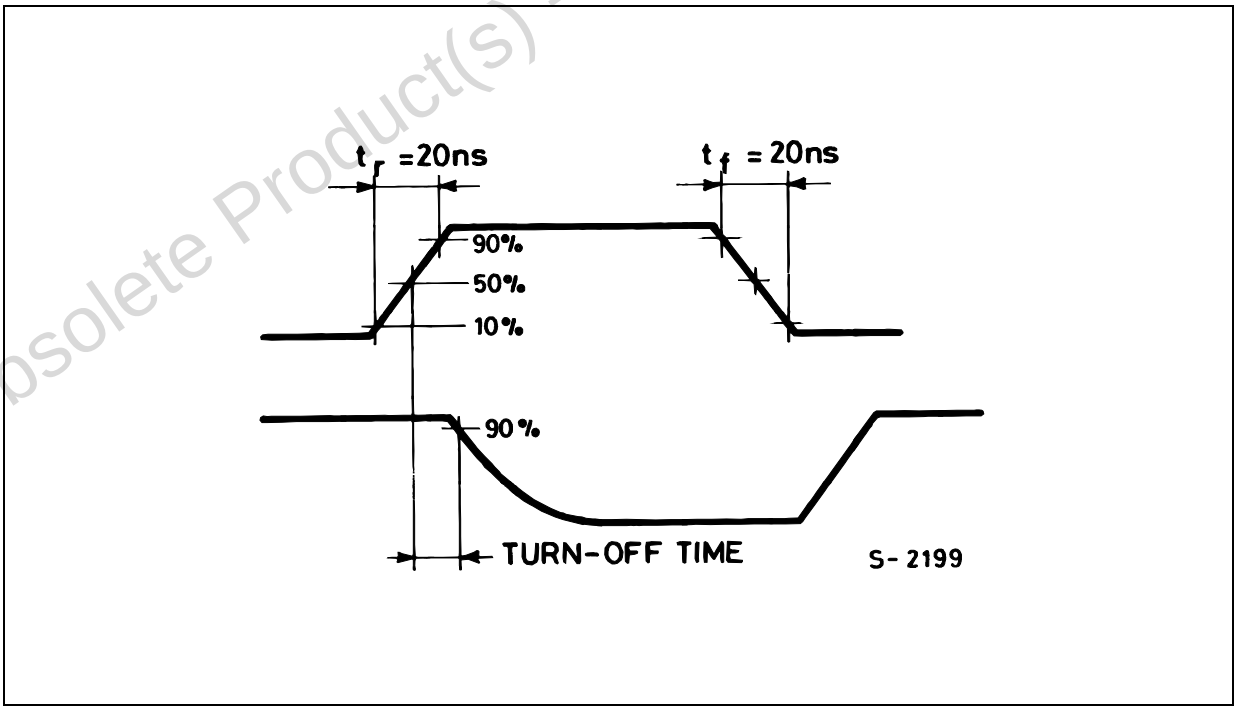
C_L = 50pF or equivalent (includes jig and probe capacitance)
R_L = 200KΩ
$R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

Obsolete Product(s) - Obsolete Product(s)

WAVEFORM : PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)



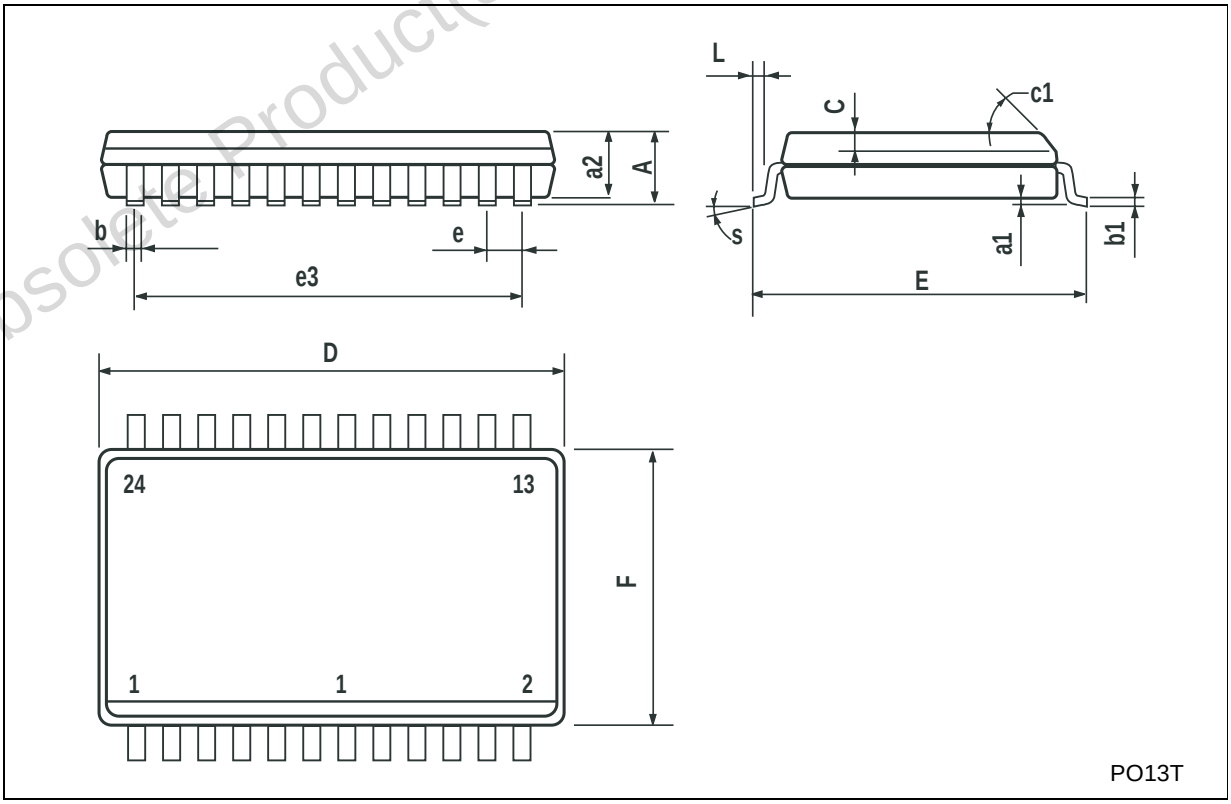
WAVEFORM : PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)



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SO-24 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			2.65			0.104
a1	0.1		0.2	0.004		0.008
a2			2.45			0.096
b	0.35		0.49	0.014		0.019
b1	0.23		0.32	0.009		0.012
C		0.5			0.020	
c1	45° (typ.)					
D	15.20		15.60	0.598		0.614
E	10.00		10.65	0.393		0.419
e		1.27			0.050	
e3		13.97			0.550	
F	7.40		7.60	0.291		0.300
L	0.50		1.27	0.020		0.050
S	8° (max.)					



PO13T

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